2SD2179

Silicon NPN epitaxial planar type

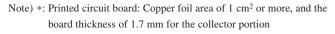
For low-frequency output amplification Complementary to 2SB1446

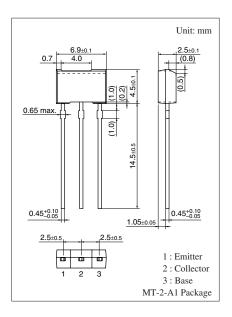
■ Features

- ullet Low collector-emitter saturation voltage $V_{CE(sat)}$
- Allowing supply with the radial taping

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	50	V	
Collector-emitter voltage (Base open)	V _{CEO}	50	V	
Emitter-base voltage (Collector open)	V_{EBO}	5	V	
Collector current	I_C	5	A	
Peak collector current	I_{CP}	7	A	
Collector power dissipation *	P _C	1	W	
Junction temperature	T_j	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	





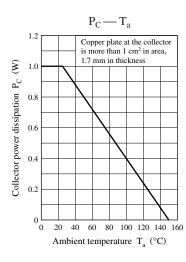
\blacksquare Electrical Characteristics $~T_a = 25^{\circ}C \pm 3^{\circ}C$

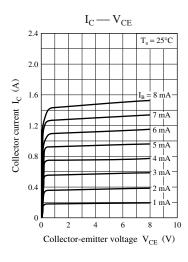
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_C = 10 \mu\text{A}, I_E = 0$	50			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 1 \text{ mA}, I_B = 0$	50			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_E = 10 \ \mu A, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 20 \text{ V}, I_{E} = 0$			0.1	μΑ
Forward current transfer ratio	h _{FE1} *2	$V_{CE} = 2 \text{ V}, I_{C} = 500 \text{ mA}$	120		340	_
	h _{FE2} *1	$V_{CE} = 2 \text{ V}, I_{C} = 2.5 \text{ A}$	60			
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_C = 2 \text{ A}, I_B = 100 \text{ mA}$		0.19	0.30	V
Base-emitter saturation voltage *1	V _{BE(sat)}	$I_C = 2 \text{ A}, I_B = 100 \text{ mA}$		0.85	1.20	V
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_{E} = -50 \text{ mA}, f = 200 \text{ MHz}$		80		MHz
Collector output capacitance	C _{ob}	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		60	70	pF
(Common base, input open circuited)						

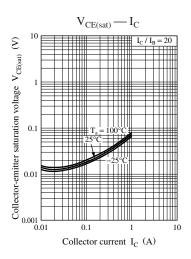
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

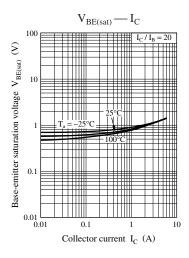
- 2. *1: Pulse measurement
 - *2: Rank classification

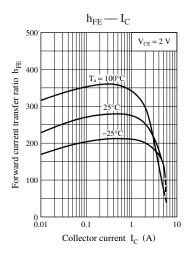
Rank	R	S
$h_{\rm FE1}$	120 to 240	170 to 340

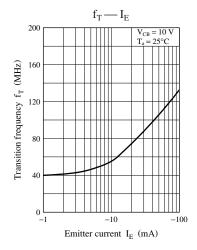


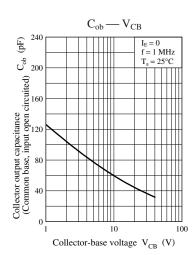












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